PCN Number: 2015092			509290	0929003B			PCN Date:		e:	01/18/2016	
Title:	Title: Assembly site move from Amkor K1 to Amkor P1 for Select Devices										
Customer Contact: PCN Manager						De	Dept: Quality Services				
Proposed 1st Ship Date: 04/18			04/18	18/2016 Estimated Sample Availability:			e	Date provided at sample request			vided at sample
Change	Change Type:										
Asse	embly Site			Design				Wafer Bump Site			o Site
Asse	embly Process				Data	Sheet	Wafer Bump Material			o Material	
	embly Material	s			Part number change			N	Wafer Bump Process		o Process
Mec	hanical Specifi	catior	I		Test Site			N	Wafer Fab Site		
Packing/Shipping/Labeling				Test Process			N	Wafer Fab Materials			
Wafer Fab Process					Process						
	PCN Details										

Description of Change:

Revision B is to announce the <u>addition</u> of new devices that were not included on the original PCN notification. These new devices are bolded and highlighted in the device list below under Product Affected Group 2. The expected first shipment date for these new devices will be 90 days from this notice for these newly added devices only.

Assembly site move from Amkor K1 to Amkor P1 for Select Devices listed in the "Product Affected" Section. Material differences are as follows:

Assembly Site	Assembly Site Origin	Assembly Country Code	Assembly Site City
Amkor K1	AMN	KR	Seoul
Amkor P1	AKR	PH	Cupang, Muntinlupa City

Material Differences: Group 1 Devices:

·	Amkor K1	Amkor P1
Mount Compound	101339127	101380679
Mold Compound	101360571	101385017

Group 2 Devices:

No material differences between sites.

Reason for Change:

Closure of the Amkor K1 assembly facility. Continuity of supply.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): None.

Changes to product identification resulting from this PCN:

TEXAS	(A) (1382)	5576		
TEXAS INSTRUMENTS		(1P)	SN74LS07NSR	
ADE IN: Malaysia		(Q)	2000 (D) 0336	
ISL 2 /260C/1 YEAR		(31T)LOT: 3959047MLA	
MSL 1 /235C/UNLIM	03/29/04	(4W) (P)	Τ Κ Υ(1Τ) 7523483SI	2
OPT: [TEM:	39	(2P) F		
.BL: 5A (L)TO	1750		CSO: SHE (21L) CCO:USA	
DEI UN (L)IV		(22L)	ASO: MLA (23L) ACO: MYS	
SEMBLY SITE CODE	S: AMN =7, AKR = 4			
SEMBLY SITE CODE	S: AMN =7, AKR = 4			
	·			
roduct Affected Gro	·			
roduct Affected Gro	·			
SSEMBLY SITE CODE roduct Affected Gro FE9006RFD roduct Affected Gro	oup 1:			
roduct Affected Gro	oup 1:	DDC118IRTCR	MM9635-LQ3/NOP	B
roduct Affected Gro FE9006RFD roduct Affected Gro	oup 1:		MM9635-LQ3/NOP SN74SSTV16859R	
oduct Affected Gro E9006RFD oduct Affected Gro 4SSTVF16859G4RG4 DS1158IRTCR	Dup 1: Dup 2: ADS1258IRTCT	DDC118IRTCR	SN74SSTV16859R	GQ8
oduct Affected Gro E9006RFD oduct Affected Gro 4SSTVF16859G4RG4 DS1158IRTCR DS1158IRTCT	Dup 1: Dup 2: ADS1258IRTCT BQ29312ARTHR DDC114IRTCR	DDC118IRTCR DDC118IRTCT HPA00025S8	SN74SSTV16859R SN74SSTV16859R	GQ8 GQR
oduct Affected Gro E9006RFD oduct Affected Gro 4SSTVF16859G4RG4 DS1158IRTCR DS1158IRTCT DS1258IRTCR	Dup 1: Dup 2: ADS1258IRTCT BQ29312ARTHR DDC114IRTCR DDC114IRTCT	DDC118IRTCR DDC118IRTCT HPA00025S8 MM9603-LQ4/N0	SN74SSTV16859R SN74SSTV16859R DPB 74SSTV16859R	GQ8 GQR IQ8G3
roduct Affected Gro E9006RFD roduct Affected Gro	Dup 1: Dup 2: ADS1258IRTCT BQ29312ARTHR DDC114IRTCR	DDC118IRTCR DDC118IRTCT HPA00025S8	SN74SSTV16859R SN74SSTV16859R OPB 74SSTV16859R 8 SN74SSTVF1685	GQ8 GQR Q8G3 9 S8

Group 1: Qualification Report Amkor K1 to P1 transfer of AFE9006RFD

Product Attributes

Attributes	Qual Device: AFE9006RFD
Assembly Site	AP1
Package Family	HTFQP
Wafer Fab Supplier	DMOS5
Wafer Process	1833 CO5

- QBS: Qual By Similarity

- Qual Device AFE9006RFD is qualified at LEVEL3-260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: AFE9006RFD
AC	Autoclave 121C	96 Hours	3/231/0
HAST	Biased HAST, 130C/85%RH	96 Hours	3/231/0
HTSL	High Temp. Storage Bake, 170C	420 Hours	3/231/0

LI	Lead Fatigue	Leads	3/66/0
LI	Lead Pull to Destruction	Leads	3/66/0
PD	Physical Dimensions		3/30/0
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0
WBP	Bond Pull	Wires	3/90/0
WBS	Ball Bond Shear	Wires	3/90/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Group 2: Qualification Report QFN transfer from Amkor K1 to Amkor P1

Product Attributes

Attributes	Qual Device: ADS1158IRTC	Qual Device: DDC118IRTCR	Qual Device: MM9603-LQ4/NOPB	Qual Device: ADC12J4000NKER / LM15851
Assembly Site	AP1	AP1	AP1	AP1
Package Family	QFN	QFN	QFN	QFN
Wafer Fab Supplier	DMOS 5	TSMC-WF2	MAINEFAB	UMC12A
Wafer Process	50HPA07	0.50UM-TSMC	C80L18M2	UMC65NM

- QBS: Qual By Similarity

- Qual Device ADC12J4000NKER / LM15851 is qualified at LEVEL3-260C

- Qual Device ADS1158IRTC is qualified at LEVEL2-260C

- Qual Device DDC118IRTCR is qualified at LEVEL3-260C

- Qual Device MM9603-LQ4/NOPB is qualified at LEVEL4-260C

- Device DDC118IRTCR contains multiple dies.

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: ADS1158IRTC	Qual Device: DDC118IRTCR	Qual Device: MM9603- LQ4/NOPB	Qual Device: ADC12J4000 NKER / LM15851
AC	Autoclave 121C	96 Hours	1/77/0	3/231/0	1/77/0	-
DS	Die Shear	-	1/10/0	3/90/0	1/10/0	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	-	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0	-	3/231/0
PD	Physical Dimensions	(per mechanical drawing)	1/5/0	3/15/0	1/5/0	3/15/0

Туре	Test Name / Condition	Duration	Qual Device: ADS1158IRTC	Qual Device: DDC118IRTCR	Qual Device: MM9603- LQ4/NOPB	Qual Device: ADC12J4000 NKER / LM15851
тс	Temperature Cycle, - 65/150C	500 Cycles	1/77/0	3/228/0	1/77/0	3/231/0
WBP	Bond Pull	Wires	1/30/0	3/90/0	1/30/0	3/90/0
WBS	Ball Bond Shear	Bonds	1/30/0	3/90/0	1/30/0	3/90/0
XRAY	X-ray	(top side only)	1/5/0	3/15/0	1/5/0	3/15/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours - The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com